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CGD944C 870 MHz, 25 dB gain power doubler amplifier Rev. 4 – 25 June 2014

Product data sheet

1. Product profile

1.1 General description

Hybrid amplifier module in a SOT115J package, operating at a supply voltage of 24 V (DC), employing Hetero Field Effect Transistor (HFET) GaAs dies.

1.2 Features and benefits

- High output capability
- Excellent linearity
- Extremely low noise
- Excellent return loss properties
- Rugged construction
- Gold metallization ensures excellent reliability

1.3 Applications

CATV systems operating in the 40 MHz to 870 MHz frequency range

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	f = 870 MHz	24	25	26	dB
I _{tot}	total current	V _B = 24 V [1]	-	450	-	mA

[1] Direct Current (DC).

2. Pinning information

Table 2. Pinning Pin Description Simplified outline Graphic symbol 1 input 2, 3 common 1 3 5 7 9 5 +V_B 7, 8 common 9 output svm095



870 MHz, 25 dB gain power doubler amplifier

3. Ordering information

Table 3. Ordering information						
Type number	Package	ackage				
	Name	Description	Version			
CGD944C	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _B	supply voltage		-	30	V
V _{i(RF)}	RF input voltage	single tone	-	75	dBmV
		132 channels flat	-	45	dBmV
T _{stg}	storage temperature		-40	+100	°C
T _{mb}	mounting base temperature		-20	+100	°C

5. Characteristics

Table 5.Characteristics

Bandwidth to 870 MHz; $V_B = 24 V (DC)$; $T_{mb} = 35 \ ^{\circ}C$; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Gp	power gain	f = 870 MHz		24	25	26	dB
SL _{sl}	slope straight line	f = 40 MHz to 870 MHz	[1]	1	-	2	dB
FL	flatness of frequency response	f = 40 MHz to 870 MHz	[2]	-	0.5	-	dB
СТВ	composite triple beat	79 + 53 flat NTSC channels	[3]	-	-68	-66	dBc
		98 flat PAL channels	[4]	-	-66	-	dBc
CSO	composite second-order distortion	79 + 53 flat NTSC channels	[3]	-	-70	-67	dBc
		98 flat PAL channels	[4]	-	-66	-	dBc
Xmod	cross modulation	79 + 53 flat NTSC channels	[3]	-	-66	-58	dB
RL _{in}	input return loss	f = 40 MHz to 80 MHz		20	-	-	dB
		f = 80 MHz to 160 MHz		19	-	-	dB
		f = 160 MHz to 320 MHz		18	-	-	dB
		f = 320 MHz to 640 MHz		18	-	-	dB
		f = 640 MHz to 870 MHz		18	-	-	dB
RL _{out}	output return loss	f = 40 MHz to 80 MHz		20	-	-	dB
		f = 80 MHz to 160 MHz		19	-	-	dB
		f = 160 MHz to 320 MHz		18	-	-	dB
		f = 320 MHz to 640 MHz		18	-	-	dB
		f = 640 MHz to 870 MHz		18	-	-	dB

870 MHz, 25 dB gain power doubler amplifier

Table 5. Characteristics ...continued

Bandwidth to 870 MHz; V_B = 24 V (DC); T_{mb} = 35 °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
NF	noise figure	f = 50 MHz	-	3.5	5.0	dB
		f = 870 MHz	-	3.5	5.0	dB
I _{tot}	total current	V _B = 24 V [5]	-	450	-	mA

[1] G_p at 870 MHz minus G_p at 40 MHz.

[2] flatness straight line (peak to valley).

[3] 79 NTSC channels (5.25 MHz to 547.25 MHz, 48 dBmV output level) + 53 NTSC channels (553.25 MHz to 870 MHz, 38 dBmV output level).

[4] $V_0 = 48 \text{ dBmV}.$

[5] Direct Current (DC).

3 of 8

NXP Semiconductors

CGD944C

870 MHz, 25 dB gain power doubler amplifier

6. Package outline

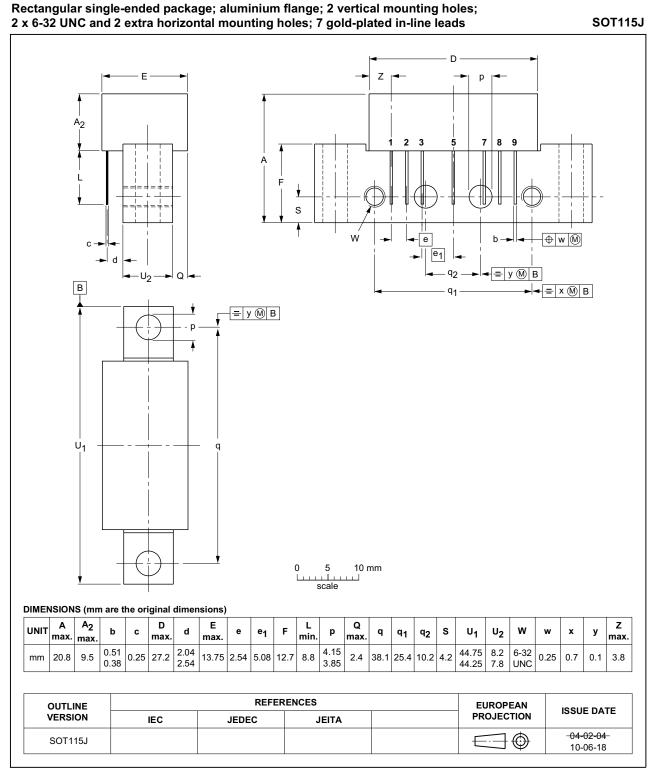


Fig 1. Package outline SOT115J

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CGD944C

870 MHz, 25 dB gain power doubler amplifier

7. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

8. Abbreviations

Table 6. Ab	Table 6. Abbreviations				
Acronym	Description				
CATV	Community Antenna TeleVision				
DC	Direct Current				
GaAs	Gallium-Arsenide				
NTSC	National Television Standard Committee				
PAL	Phase-Alternation Line				
RF	Radio Frequency				
UNC	UNified Coarse thread				

9. Revision history

Table 7.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
CGD944C v.4	20140625	Product data sheet	-	CGD944C v.3
Modifications:	 <u>Table note 3 on page 3</u>: 997.25 MHz has been changed to 870 MHz. <u>Section 7 on page 5</u>: The ESD warning has been moved here from the front page. Legal texts have been updated. 			
CGD944C v.3	20100929	Product data sheet	-	CGD944C v.2
CGD944C v.2	20091116	Product data sheet	-	CGD944C v.1
CGD944C v.1	20070606	Product data sheet	-	-

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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CGD944C

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7 of 8

CGD944C

870 MHz, 25 dB gain power doubler amplifier

12. Contents

1	Product profile 1
1.1	General description 1
1.2	Features and benefits 1
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 1
3	Ordering information 2
4	Limiting values 2
5	Characteristics 2
6	Package outline 4
7	Handling information 5
8	Abbreviations 5
9	Revision history 5
10	Legal information 6
10.1	Data sheet status 6
10.2	Definitions6
10.3	Disclaimers 6
10.4	Trademarks 7
11	Contact information 7
12	Contents

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